NSN 5962-01-383-2881

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View Online at https://aerobasegroup.com/nsn/5962-01-383-2881

Body Length:
Between 1.270 inches and 1.290 inches
Body Width:
Between 0.590 inches and 0.610 inches
Body Height:
Between 0.205 inches and 0.225 inches
Maximum Power Dissipation Rating:
1.04 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Lgm-030f/g, 118a
Features Provided:
Bipolar and burn in, mil-std-883, class b and electrostatic sensitive and monolithic and programmed and tested to mil-std-883
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Criticality Code Justification:

Criticality Code Justification

Feat

Case Outline Source And Designator:

D-3 mil-m-38510

Current Rating Per Characteristic:

190.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

Programmable read only memory (prom) anti-intrusion alarm set operational software

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source and 5.5 volts input

Capitance Rating Per Characteristic:

10.00 input picofarads

Time Rating Per Chacteristic:

100.00 nanoseconds propagation delay and 100.00 nanoseconds access

Memory Device Type:

Prom

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Special Features:

Esd; altered item programmed using 14933/82009a1jx (which is substitute for 82009i1jx) using d180-18228-1

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0